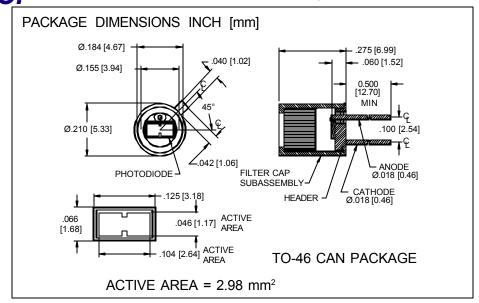
PHOTONIC Silicon Photodiode, Filter Combination Photoconductive **DETECTORS INC.** 500 nm (blue color) Type PDV-C405-46





RESPONSIVITY (A/W)

FEATURES

- 500 nm CWL
- 70 nm FWHM
- Large active area

DESCRIPTION

The **PDV-C405-46** is a silicon, PIN planar diffused, photodiode with a blue color 500 nm +/- 2 nm CWL wide band interference filter and a wide 70 nm half bandwidth. Ideal for color meters, & photometry and radiometry measurment applications.

APPLICATIONS

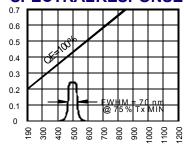
- Blue color matching
- Color meters
- Film processing

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		100	V
T_{STG}	Storage Temperature	-20	+85	∘C
То	Operating Temperature Range	-15	+70	⊙C
Ts	Soldering Temperature*		+240	∘C
IL	Light Current		500	mA

^{*1/16} inch from case for 3 secs max

SPECTRALRESPONSE



WAVELENGTH(nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS			
Isc	Short Circuit Current***	H = 100 fc, 2850 K	40	45		μ A			
ΙD	Dark Current	H = 0, V _R = 10 V		.15	1.0	nA			
RsH	Shunt Resistance	H = 0, V _R = 10 mV	.5	1.0		GΩ			
TC Rsh	RsH Temp. Coefficient	H = 0, V _R = 10 mV		-8		%/℃			
CJ	Junction Capacitance	H = 0, V _R = 10 V**		10		рF			
CWL	Center Wavelength	(CWL, λ o) +/- 2 nm		500		nm			
HBW	Half Bandwidth	(FWHM)		70		nm			
V _{BR}	Breakdown Voltage	I = 10 μA	70	100		V			
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		1.5x10 ⁻¹⁴		W/√ _{Hz}			
tr	Response Time	$RL = 1 K\Omega V_R = 50 V$		10		nS			

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f=1MHz, ***without filter [FORM NO. 100-PDV-C405-46 REV N/C]